NSN 5961-00-359-5615

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| Inclosure Material: |
|---|
| Metal |
| Overall Length: |
| 0.210 inches |
| Terminal Length: |
| 0.500 inches |
| Overall Diameter: |
| 0.230 inches |
| Internal Configuration: |
| Field effect |
| Joint Electronic Device Engineering Council/jedec/case Outline Designation: |
| To-18 |
| Mounting Method: |
| Terminal |
| Terminal Circle Diameter: |
| 0.100 inches |
| Features Provided: |
| Hermetically sealed case |
| Semiconductor Material: |
| Silicon |
| Voltage Rating In Volts Per Characteristic: |
| 50.0 drain to gate voltage |
| Current Rating Per Characteristic: |
| 50.00 milliamperes gate current |
| Power Rating Per Characteristic: |
| 150.0 milliwatts total device dissipation |
| Maximum Operating Tempurature Per Measurement Point: |
| 125.0 degrees celsius junction |
| Terminal Type And Quantity: |
| 4 uninsulated wire lead |
| Shelf Life: |
| N/a |
| Unit Of Measure: |
| |
| Demilitarization: |
| No |
| Fiig: |
| A110a0 |
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